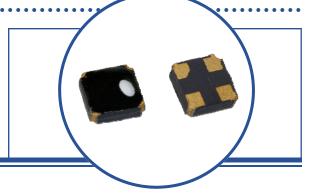
Surface Mount Optically Coupled Isolator OPI210, OPI211



Features:

- 1kV electrical isolation
- Miniature package ideal for surface mount applications
- TTL, DTL compatible
- High DC Current Transfer ratio



Description:

Each Optically coupled isolator in this data sheet contains an infrared Light Emitting Diode (LED) and a NPN silicon Photosensor. The **OPI210** and **OPI211** devices have 890 nm Light Emitting Diode (LED) and NPN phototransistor and coupled on an FR-4 substrate. The devices are made with a sealed internal optically transmissive path between the LED and the photosensor.

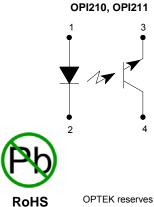
The OPI210 and OPI211 are identical except for the DC current transfer ratio. Both were designed with high reliability in mind and are ideally suited for use in MIL-STD-883 applications. The devices may be mounted using either silver or gold filled epoxies. The top of the device is covered with a silicone material and is very sensitive to acetone type cleaning material.

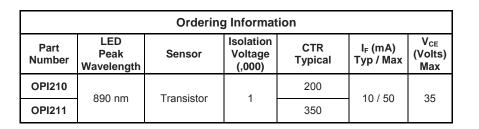
This series is designed for transmission of information between one power supply voltage to another where the potentials during surge conditions are not greater than the guaranteed isolation voltage.

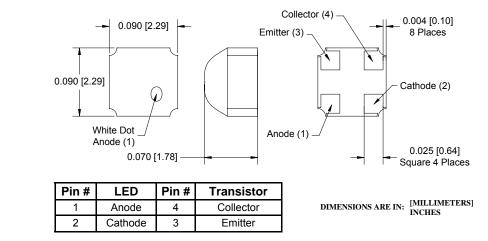
Contact your local representative or OPTEK for more information.

Applications:

- Military equipment
- High-Reliability environments
- High voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment







OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.



Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage	e Temperature					-65° C to +150° C
Operating Temperature						-55° C to +125° C
Input-to-Output Isolation Voltage ⁽¹⁾⁽²⁾						± 1 kVDC
Lead Soldering Temperature (1/16" (1.6 mm) from case for 5 seconds with soldering iron) ⁽³⁾						ing iron) ⁽³⁾ 260° C
nput Diod	e					
Forward DC Current ⁽⁴⁾						50 mA
Reverse DC Voltage						3 V
Power Dissipation ⁽⁵⁾						60 mW
Output Ph	otosensor					
Collector-Emitter Voltage						35 V
Emitter-Collector Voltage						7.0 V
Power Dissipation ⁽⁶⁾						100 mW
Electrica	al Characteristics ($T_A = 25^{\circ}$ C unles	ss othe	rwise n	oted)		
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
STINDUL		IVITIN	ITP	IVIAA	UNITS	
	le (See OP265 for additional information -				UNITS	TEST CONDITIONS
					V	I _F = 10 mA
Input Diod	le (See OP265 for additional information -		rence o	nly)		
Input Diod	le (See OP265 for additional information -	for refe - -	rence o - -	nly) 1.6 100	V µA	I _F = 10 mA
Input Diod	le (See OP265 for additional information - Forward Voltage Reverse Current	for refe - -	rence o - -	nly) 1.6 100	V µA	I _F = 10 mA
Input Diod V _F I _R Output Ph	le (See OP265 for additional information - Forward Voltage Reverse Current otosensor (See OP505 for additional info	for refe - - prmation	rence o - - - for re	nly) 1.6 100 ference	V µA only)	I _F = 10 mA V _R = 2 V
Input Diod V _F I _R Output Ph V _{(BR)CEO}	le (See OP265 for additional information - Forward Voltage Reverse Current otosensor (See OP505 for additional info Collector-Emitter Breakdown Voltage	for refe - - prmation 35	rence o - - - for re 80	nly) 1.6 100 ference	V µA only) V	$I_F = 10 \text{ mA}$ $V_R = 2 \text{ V}$ $I_C = 100 \text{ µA}, I_F = 0$
Input Dioc V_F I_R Output Ph $V_{(BR)CEO}$ $V_{(BR)ECO}$	le (See OP265 for additional information - Forward Voltage Reverse Current otosensor (See OP505 for additional info Collector-Emitter Breakdown Voltage Emitter-Collector Breakdown Voltage	for refe - - prmation 35	rence o - - - for re 80 10	nly) 1.6 100 ference -	V μA only) V V	$I_F = 10 \text{ mA}$ $V_R = 2 \text{ V}$ $I_C = 100 \mu\text{A}, I_F = 0$ $I_E = 100 \mu\text{A}, I_F = 0$
Input Dioc V _F I _R Output Ph V _{(BR)CEO} V _{(BR)ECO} I _{CEO}	le (See OP265 for additional information - Forward Voltage Reverse Current otosensor (See OP505 for additional info Collector-Emitter Breakdown Voltage Emitter-Collector Breakdown Voltage	for refe - - prmation 35	rence o - - - for re 80 10	nly) 1.6 100 ference -	V μA only) V V	$I_F = 10 \text{ mA}$ $V_R = 2 \text{ V}$ $I_C = 100 \mu\text{A}, I_F = 0$ $I_E = 100 \mu\text{A}, I_F = 0$
Input Dioc V_F I_R Output Ph $V_{(BR)CEO}$ $V_{(BR)ECO}$ I_{CEO} Coupled	le (See OP265 for additional information - Forward Voltage Reverse Current otosensor (See OP505 for additional info Collector-Emitter Breakdown Voltage Emitter-Collector Breakdown Voltage Collector-Emitter Dark Current DC Current Transfer Ratio OPI210	for refe - - ormation 35 7 - 50	rence o - - for re 80 10 20	nly) 1.6 100 ference - - 100	V μA only) V V nA	$I_{F} = 10 \text{ mA}$ $V_{R} = 2 \text{ V}$ $I_{C} = 100 \mu\text{A}, I_{F} = 0$ $I_{E} = 100 \mu\text{A}, I_{F} = 0$ $V_{CE} = 20 V, I_{F} = 0$

Notes:

(1) Measured with input and output leads shorted. Typical input/output capacitance is 0.06 pF.

(2) UL recognition is for 3500 VAC for one minute.

(3) RMA flux is recommended. The duration can be extended to 10 seconds maximum when flow soldering.

(4) Derate linearly 0.67 mA/°C above 25°C.

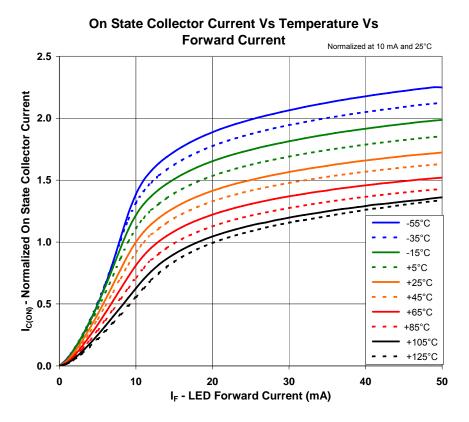
(5) Derate linearly 0.83 mA/°C above 25°C.

(6) Derate linearly 1.67 mA/°C above 25°C.

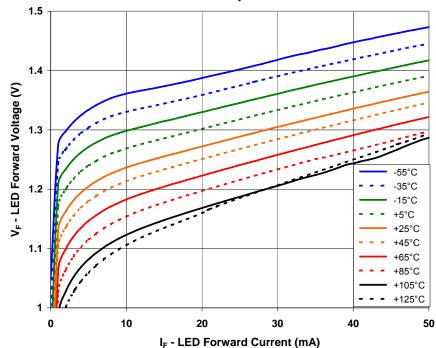
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Surface Mount Optically Coupled Isolator OPI210, OPI211





Forward Voltage Vs Forward Current Vs Ambient Temperature



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